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Tutorial notes for the evaluation of thermoelectric quantum bounds in ideal nanostructures

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The wave-like nature of electrons leads to the existence of upper bounds on the thermoelectric response of nanostructured devices [R. S. Whitney, Phys. Rev. Lett. **112**, 130601 (2014); Phys. Rev. B **91**, 115425 (2015)]. This fundamental result, not present in classical thermodynamics, was demonstrated exploiting a two-terminal device modelled by non-linear scattering theory. In the present paper, we consider non-linear quantum transport through the same type of device working both as thermal machine and as refrigerator. For both operations, starting from charge and heat current expressions, we provide analytic quantum bounds for power exchanged, thermal currents and device efficiencies. For this purpose, we adopt a transmission function that maximizes the engine efficiency for given power output. For the optimal boxcar- or theta function-transmission shapes, we provide in a tutorial way an explicit deduction of the quantum bound expressions reported in the above cited papers.

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I. INTRODUCTION

Nanoscale thermoelectric (TE) engines for both power production and refrigeration have attracted great interest since the papers of Hicks and Dresselhaus[1–3] and of Mahan and Sofo[4], who evidenced the effect of reduced dimensionality on the electronic density of states to increase the TE efficiency. In linear regime conditions, i.e., for low temperature gradients and small applied voltage biases, the thermoelectric performance is represented by the dimensionless figure of merit[5] $ZT = \sigma S^2 T/(\kappa_{el} + \kappa_{ph})$, where σ is the electronic conductance, S the Seebeck coefficient, T the absolute temperature, and κ_{el} (κ_{ph}) the electronic (phonon) thermal conductance. Attempts to reach high values of ZT by modifying the physical parameters entering in its definition by device design and appropriate choice of materials have shown limits due to their often competing behavior as function of temperature[6–15]. In fact, for nanostructures the nonlinear response regime is of primary interest because at the nanometer scale temperature and bias gradients may become very large. Description of thermoelectric phenomena at the nanoscale as in the case of quantum wells[16], quantum dots[17,18], nanowires[19], molecular junctions[20] or superlattices[21] deserves to consider fundamental aspects connected with quantum effects, thermodynamics and scale of electron thermalization[22–27]. Moreover, quantum transport formalism provides an appropriate microscopic description of charges and heat flows [28–30]. In particular, for non-interacting systems, calculations of thermoelectric functions also in multiterminal cases and in the presence of magnetic fields [31,32] can be done by means of the Landauer-Büttiker approach, which provides expressions for electron

and heat currents in terms of transmission properties and contains the microscopic physics of the system. In the case many-body effects are important, the most appropriate approach is based on the Keldysh formalism[28–30,33–38].

In the present paper, we consider a two-terminal device made of two reservoirs (left and right) at different temperatures and chemical potentials, (T_L, μ_L) and (T_R, μ_R), and connected to a central scattering region by perfect leads, see Fig. 1. We suppose that the device is in quantum coherent conditions, with no electron-phonon and electron-electron interactions. In the above quantum coherent regime, the Büttiker-Landauer scattering theory[23,39,40] is used for the description of heat currents and electrical currents. This theory is valid for linear as well for non-linear regimes. Transport is described by the transmission function $\mathcal{T}(E)$ of the scattering region.

A further important aspect connected with the quantum nature of electrons has been highlighted by Whitney[41,42] and addressed in what follows. The story goes back to the work of Bekenstein[43] on the relation between information flow and energy flow rates, and the study of Lebedev and Levitin[44](1966) concerning the transmission of an electromagnetic field in one dimension and a single-channel communication system. In a successive work by means of information theory analogy, Pendry[45](1983) found a fundamental upper bound on the heat flow through a quantum system between a left reservoir at temperature T and a right reservoir at T=0: $I_Q^{(\mathrm{Pendry})} \equiv (k_\mathrm{B}T)^2 N\pi^2/6h$, where k_B is the Boltzmann constant, N is the number of channels in the cross section through which current flows, and h is the Planck constant.

Based on this result, for quantum thermoelectricity described by Landauer scattering theory, Whitney extended the Pendry's result by considering the heat flow through a scattering system between two reservoirs at different temperatures and at the same chemical potential. He found a quantum bound on the power output and then, by an optimization process of the transmission function, he obtained an upper bound for the efficiency at given power output for heat engines and for refrigerators.

In the present paper, we obtain exactly the same results with a didactic step-by-step procedure.

In Sec. II, we provide basic expressions for thermoelectric transport through a two-terminal mesoscopic electronic system. These expressions are useful for the determination of the existence of quantum bounds in currents, exchanged power and machine efficiencies, and for their analytic evaluation. Section III and Sec. IV present the explicit expressions for the above mentioned quantities. From them, it is easy to individuate the presence of upper values (quantum bounds) in thermoelectric transport. Sec. V and Sec. VI address the same above problems in the case of very low power exchanged by thermal machines and refrigerators, respectively. Finally, Sec. VII concludes.

II. MODEL AND BASIC EXPRESSIONS FOR THERMOELECTRIC TRANSPORT IN NANOSCALE STRUCTURES

In this section, we consider transport through a two-terminal mesoscopic electronic system coupled to two reservoirs, characterized by N transmitting channels, with total transmission function $\mathcal{T}(E) \leq N$. Without loss of generality, we assume that the temperature of the left reservoir T_L is higher than that of the right reservoir T_R. We examine in detail the case $\mu_L < \mu_R$. The opposite case $\mu_L > \mu_R$ could be envisaged, with appropriate modifications, from the discussion here presented.

The *left* or the *right* thermal currents $I_Q^{(L)}$ and $I_Q^{(R)}$, and the output or input power $\mathcal{P}$, related to transport of electrons across the mesoscopic device are given by the Landauer expressions valid for linear and non-liner regimes[39,46–48]

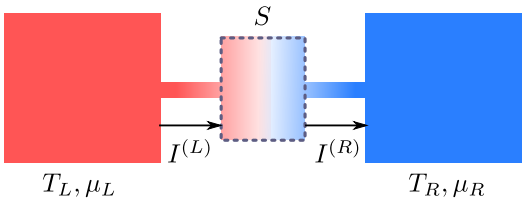


FIG. 1. Schematic representation of the scattering region S connected to two reservoirs. We consider positive the direction for the currents from the left to right.

$$I_Q^{(L,R)} = \frac{1}{h}\int_{-\infty}^{+\infty} dE(E-\mu_{L,R})\,\mathcal{T}(E)\,[f_L(E)-f_R(E)] \tag{1a}$$

$$\mathcal{P} = I_Q^{(L)} - I_Q^{(R)} = \frac{1}{h}\,(\mu_R-\mu_L)\int_{-\infty}^{+\infty} dE\,\mathcal{T}(E)\,[f_L(E)-f_R(E)]\ , \tag{1b}$$

where $f_{L,R}(E) = 1/[\mathrm{e}^{(E-\mu_{(L,R)})/(k_\mathrm{B}T_{(L,R)})}+1]$ are the Fermi-Dirac distribution functions in the two leads. The applied bias potential $\Delta V = V_L - V_R$ and the chemical potentials difference $\Delta\mu = \mu_L - \mu_R$ are related by $(-e)\Delta V = \Delta\mu$. The device operates as *thermal machine*, i.e, in the *power production regime* $\mathcal{P} = \mathcal{P}_{out} > 0$, when the heat is extracted from the hot reservoir and released to the cold one, while part of the thermal energy can be converted into usable power. We have thus the conditions

$$I_Q^{(L)} > I_Q^{(R)} > 0\ . \tag{2}$$

The efficiency of the device in this mode is defined as the ratio of the usable power to the heat extracted from the hot reservoir

$$\eta^{(tm)} = \frac{\mathcal{P}_{out}}{I_Q^{(L)}} = \frac{I_Q^{(L)} - I_Q^{(R)}}{I_Q^{(L)}} \le \eta_c^{(tm)}\ . \tag{3}$$

As a consequence, the efficiency of the thermal machine cannot exceed the Carnot efficiency $\eta_c^{(tm)} \equiv (T_L - T_R)/T_L$. The device operates as a refrigerator if heat is extracted from the cold reservoir and released into the hot reservoir, with the absorption of external energy converted into wasted heat. In this case, *left thermal current, right thermal current and absorbed power ($\mathcal{P} = \mathcal{P}_{in}$) are all negative quantities*:

$$I_Q^{(L)} < I_Q^{(R)} < 0\ , \tag{4}$$

and the efficiency (coefficient of performance) of the refrigerator is given by

$$\eta^{(refr)} = \frac{I_Q^{(R)}}{\mathcal{P}_{in}} = \frac{I_Q^{(R)}}{I_Q^{(L)} - I_Q^{(R)}} \le \eta_c^{(refr)}\ . \tag{5}$$

As a consequence, the upper *thermodynamic bound* of the refrigeration efficiency cannot exceed the performance of the Carnot refrigerator $\eta_c^{(refr)} \equiv T_R/(T_L - T_R)$.

From the transport Eqs. (1), it is apparent the basic role played by $\mathcal{T}(E)$ and by the difference of the Fermi functions of the left and right leads electrodes $f_{LR}(E) \equiv f_L(E) - f_R(E)$. We observe that

$$f_{LR}(E) > 0 \qquad \text{if} \qquad E > \frac{\mu_R\,T_L - \mu_L\,T_R}{T_L - T_R} \equiv \varepsilon_0\ , \tag{6}$$

where the energy ε_0 separates the region of positive values of $f_{LR}(E)$ from the region of negative values. The position of ε_0 with respect to the two chemical potentials is

$$\varepsilon_0 - \mu_{L,R} = \frac{T_{L,R}}{T_L - T_R}(\mu_R - \mu_L) > 0\ . \tag{7}$$

Therefore, ε_0 is at the right of the chemical potentials of the two reservoirs, as shown in Fig. 2.

From Eq. (7), we have

$$\frac{\varepsilon_0 - \mu_L}{k_\mathrm{B}T_L} = \frac{\varepsilon_0 - \mu_R}{k_\mathrm{B}T_R} = \frac{\mu_R - \mu_L}{k_\mathrm{B}(T_L - T_R)} \equiv x_0\ , \tag{8}$$

where, as shown below, the quantity x_0 is important in the definition of quantum bounds for currents and exchanged power.

It is worth noticing that at the energy ε_0 the occupation of states in the two electron reservoirs is the same and the two reservoirs can exchange electrons reversibly. As evident from Eqs. (1), for E= ε_0 the exchanged power $\mathcal{P}$, becomes 0 and the thermal machine efficiency reaches the Carnot limit[49,50]:

$$\eta^{(tm)} = \mathcal{P}/(I_Q^L) = (\mu_R - \mu_L)/(\varepsilon_0 - \mu_L) = 1 - T_R/T_L = \eta_C^{(tm)}\ . \tag{9}$$

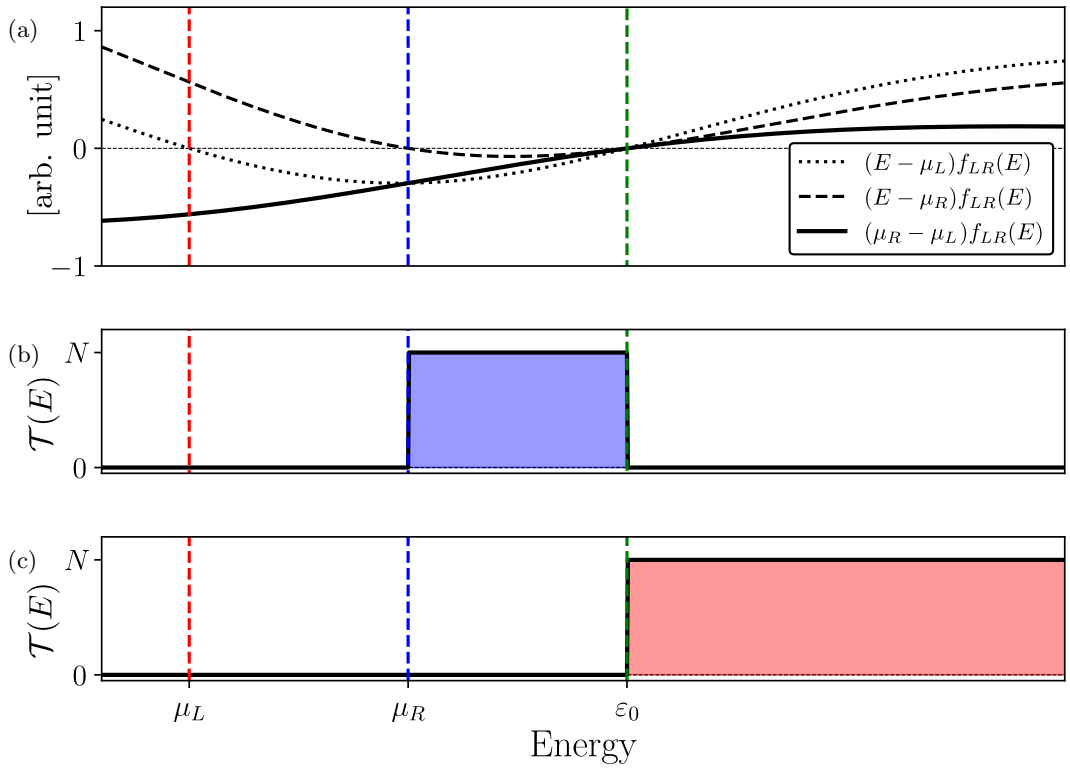


FIG. 2. (a) Representation on the energy axis of the functions $(E-\mu_L)f_{LR}(E)$ (pointed line), $(E-\mu_R)f_{LR}(E)$ (dashed line), and $(\mu_R-\mu_L)f_{LR}(E)$ (solid line) which enter in the definition of the thermal currents, $I_Q^{(L)}$ and $I_Q^{(R)}$, and power $\mathcal{P}$ respectively (see Eq. (1a) and Eq. (1b)), in the case $T_L > T_R$ and $\mu_L < \mu_R$. (b) Optimal (box-like shape) transmission function for the ideal refrigerator. It is different from zero, and equal to the number of transmission channels N, only in the region $\mu_R \leq E \leq \varepsilon_0$ where both $I_Q^{(L)}$ and $I_Q^{(R)}$ are negative. (c) Optimal (step-like shape) transmission function for the ideal thermal machine. It is different from zero, and equal to the number of transmission channels N, only when $E \geq \varepsilon_0$, where both $I_Q^{(L)}$ and $I_Q^{(R)}$ are positive. Without loss of generality, for this figure we have chosen $T_L = 600$ K, $T_R = 300$ K, $\mu_L = 0$ eV, and $\mu_R = 0.025$ eV.

This coincides with the results of Mahan and Sofo for a delta-like shape transmission function filtering at the energy ε_0 [4,51] and corresponds to reversible transport with zero entropy production and zero output power. Similar considerations can be done for the coefficient of performance in the refrigerator machine.

A main result of Whitney is the proof that the optimal efficiency of a thermal machine at a chosen power output is obtained when the transmission function has a square shape, which allows transmission of electrons only in a chosen energy range, the width of the square being determined by the maximum possible efficiency for the given power output[41,42,52], i.e., a narrow boxcar for small power output, up to a θ-function shape for high power outputs. In the following, we shall assume the above shapes for the $\mathcal{T}(E)$.

III. QUANTUM TRANSPORT THROUGH IDEAL THERMAL MACHINES

A. Quantum bounds for power generation

Consider a system in the *power generation regime* $\mathcal{P} > 0$. The expression of the output power is given in Eq. (1b), whose maximal value is obtained restricting the integral to the positive region of $f_{LR}(E)$, see Fig. 2, and assuming the value of N for the total "optimal" transmission function in the whole domain $[\varepsilon_0, \infty]$, i.e., a step-like shape for the transmission function of the *ideal power generator*. For this device the output power is given by the expression

$$\mathcal{P}_{out} = \frac{N}{h}\,(\mu_R - \mu_L)\int_{\varepsilon_0}^{+\infty} dE\, f_{LR}(E) = \frac{N}{h}\,k_{\rm B}^2(T_L - T_R)^2\, x_0 \ln(1+e^{-x_0})\ , \tag{10}$$

where we exploited the definite integral $\int_{E_0}^{+\infty} f(E)\,dE = k_{\rm B}T \ln\left[1+e^{-(E_0-\mu)/k_{\rm B}T}\right]$. We have now to optimize Eq. (10) when the chemical potentials of the leads are changed, at fixed temperatures T_L and T_R, i.e., to maximize the function $F(x_0) = x_0 \ln(1+e^{-x_0})$. With numerical methods, we find $dF(x_0)/dx_0 = 0$ for $\bar{x}_0 = 1.146$ and $F(\bar{x}_0) \cong 0.316$. In summary, the quantum bound for power production reads

$$\mathcal{P}_{out}^{(QB)} = C_0 \frac{N}{h} k_{\rm B}^2 (T_L - T_R)^2 \qquad \text{with} \qquad C_0 \equiv 0.316 \ , \tag{11}$$

in complete agreement with Eq.(43) and Eq.(44) of ref.[42].

B. Quantum bounds for left thermal currents

The general expression of the left thermal current is given by Eq. (1a). Its value for a device in the *ideal power generation regime* is obtained restricting the integral to the positive region of $f_{LR}(E)$, and assuming, as before, the value of N for the total transmission function in the whole domain $[\varepsilon_0, \infty]$. It follows that

$$I_Q^{(L)} = \frac{N}{h} \int_{\varepsilon_0}^{+\infty} dE\,(E-\mu_L) f_{LR}(E) \ . \tag{12}$$

This integral is evaluated analytically by using the elementary properties of the poly-logarithm functions of order one, $\mathrm{Li}_1(z)$, and of order two, $\mathrm{Li}_2(z)$, (see App. A). Equation (12) for $I_Q^{(L)}$ finally becomes (see App. B)

$$I_Q^{(L)} = \frac{N}{h} k_{\rm B}^2 T_L (T_L - T_R)\, x_0 \ln(1+e^{-x_0}) - \frac{N}{h} k_{\rm B}^2 (T_L^2 - T_R^2)\, \mathrm{Li}_2(-e^{-x_0}) \ . \tag{13}$$

The thermal current depends on the difference of the chemical potentials, on the difference of the temperatures, on the left current and on the average temperature. In the particular case $T_L = T_R$, the value of x_0 approaches ∞ and no thermal current flows through the device.

To establish the quantum bound of the left thermal current with an eye to Eq. (13), we have to maximize the function

$$G(x_0) = T_L\, x_0 \ln(1+e^{-x_0}) - (T_L + T_R)\, \mathrm{Li}_2(-e^{-x_0}) \ . \tag{14}$$

The derivative of the above function, with the help of (A3), becomes

$$dG(x_0)/dx_0 = -T_L x_0/(e^{x_0}+1) - T_R \ln(1+e^{-x_0}) < 0 \quad . \tag{15}$$

Since x_0 is limited to values greater or equal to zero, we argue that the maximum value of the function $G(x_0)$ occurs for $x_0 = 0$. By replacing this value into Eq. (13), we obtain that the left thermal current generated in the power generation regime is limited by the quantum bound

$$I_Q^{(L)(QB)} = \frac{N\pi^2}{12} \frac{k_{\rm B}^2}{h} (T_L^2 - T_R^2) \ , \tag{16}$$

where we have used $\mathrm{Li}_2(-1) = -\pi^2/12$.

C. Quantum bounds for right thermal currents

The maximal value of the right thermal current of Eq. (1a) in the power generation regime can be evaluated by following step-by-step the procedure applied to the expression of the left thermal current of Eq. (12). For the right thermal current, we obtain the expression

$$I_Q^{(R)} = \frac{N}{h} k_{\rm B}^2 T_R (T_L - T_R)\, x_0 \ln(1+e^{-x_0}) - \frac{N}{h} k_{\rm B}^2 (T_L^2 - T_R^2)\, \mathrm{Li}_2(-e^{-x_0}) \ . \tag{17}$$

By setting $\mu_R = \mu_L$, i.e., $x_0 = 0$ in Eq. (17), we obtain that the maximal value of the right thermal current generated by a device in the power generation regime presents the quantum bound

$$I_Q^{(R)(QB)} = \frac{N\pi^2}{12} \frac{k_{\rm B}^2}{h} (T_L^2 - T_R^2) \ . \tag{18}$$

This quantum bound is of course the same as the quantum bound for the left thermal current, in fact, when the two chemical potentials are equal, also the two thermal currents must be equal.

D. Quantum bound for efficiency in a power generator

The expression of the efficiency of the thermal machine reads

$$\eta^{(tm)} = \frac{\mathcal{P}_{out}}{I_Q^{(L)}} = \frac{(T_L - T_R)\, x_0 \ln(1+e^{-x_0})}{T_L\, x_0 \ln(1+e^{-x_0}) - (T_L+T_R)\mathrm{Li}_2(-e^{-x_0})} = \eta_C^{(tm)} \frac{1}{1 - \dfrac{(T_L+T_R)}{T_L}\dfrac{\mathrm{Li}_2(-e^{-x_0})}{x_0 \ln(1+e^{-x_0})}} \,. \tag{19}$$

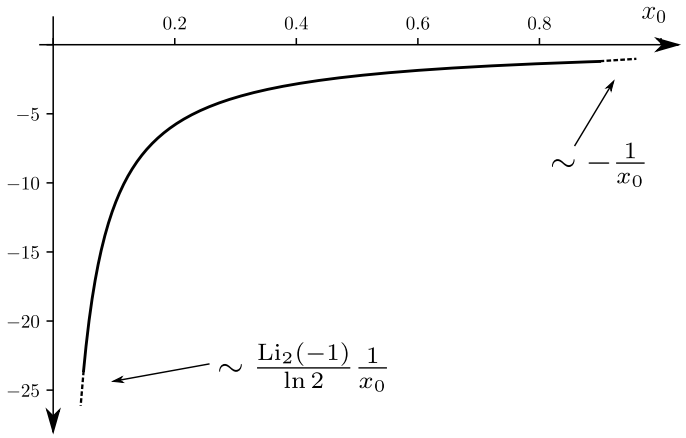


FIG. 3. Behavior of the function $\dfrac{\mathrm{Li}_2(-e^{-x_0})}{x_0 \ln(1+e^{-x_0})}$.

When $\mu_L \approx \mu_R$, $\eta^{(tm)} \approx 0$ and no efficient thermal machine is possible. On the contrary the maximal efficiency of Eq. (19) is obtained when $x_0 \to \infty$, see Fig. 3. The maximal efficiency equals the thermodynamic bound of the Carnot machine, while the production of power is vanishingly small.

IV. QUANTUM TRANSPORT THROUGH IDEAL REFRIGERATORS

A. Absence of quantum bounds for the absorbed power

In this section, we study transport through a device perfectly transparent in the refrigeration domain and perfectly opaque elsewhere. For a device operating in the ideal refrigeration mode, i.e., with left thermal current, right thermal current and absorbed power all negative quantities, we restrict the integral defining their expressions to the negative region of $f_{LR}(E)$ in the domain $[\mu_R, \varepsilon_0]$, and assuming the "optimal" value of N for the transmission function there, see Fig. 2, i.e., for the transmission function it is assumed a box-like shape of width $(\varepsilon_0 - \mu_R)$: $\mathcal{T}(E) = N$ for $\mu_R < E < \varepsilon_0$ and $\mathcal{T}(E) = 0$ elsewhere. In this case, the right thermal current is maximal as requested to have a maximal cooling of the right reservoirs. For the described nanostructure device in the refrigeration regime ($\mathcal{P} < 0$), the expression of the absorbed (input) power reads

$$\mathcal{P}_{in} = \frac{N}{h}(\mu_R - \mu_L) \int_{\mu_R}^{\varepsilon_0} dE\, f_{LR}(E) \,. \tag{20}$$

The above integral can be performed analytically (see App. B) and gives

$$\mathcal{P}_{in} = \frac{N(\mu_R - \mu_L)}{h}\left[-k_B T_L \ln(1+e^{-x_0}) + k_B T_L \ln(1+e^{-x_1}) + k_B T_R \ln(1+e^{-x_0}) - k_B T_R \ln 2\right] \,, \tag{21}$$

where $x_1 \equiv (\mu_R - \mu_L)/(k_B T_L)$. In particular, we remark

$$\mathcal{P}_{in} = -\frac{N(\mu_R - \mu_L)}{h} k_B T_R \ln 2 + \ldots \qquad \text{for} \qquad \mu_R - \mu_L \to +\infty \,. \tag{22}$$

For arbitrary large difference of the chemical potentials, it is evident that no bound occurs for the absorbed power. This is different from the situation of thermal machine, where an upper bound occurs for power generation.

B. Left thermal current: absence of quantum bound

The left thermal current in the ideal refrigerator is

$$I_Q^{(L)} = \frac{N}{h}\int_{\mu_R}^{\varepsilon_0} dE\,(E-\mu_L) f_{LR}(E)\ . \tag{23}$$

Details of the manipulation of the above equation are reported in App. B. The final expression of Eq. (23) is

$$\begin{aligned} I_Q^{(L)} = \frac{N}{h}\Big[&- k_{\rm B}T_R(\mu_R-\mu_L)\ln 2 + k_{\rm B}^2 T_L^2 x_1 \ln(1+{\rm e}^{-x_1}) + k_{\rm B}^2(T_L^2-T_R^2)\,{\rm Li}_2(-{\rm e}^{-x_0}) \\ &- k_{\rm B}^2 T_L(T_L-T_R)x_0\ln(1+{\rm e}^{-x_0}) - k_{\rm B}^2 T_L^2\,{\rm Li}_2(-{\rm e}^{-x_1}) + k_{\rm B}^2 T_R^2\,{\rm Li}_2(-1)\Big]\ . \end{aligned} \tag{24}$$

In particular, remembering the definitions of x_0 and x_1, we find the leading terms

$$I_Q^{(L)} = -\frac{N}{h}\,k_{\rm B}T_R\,(\mu_R-\mu_L)\,\ln 2 + \frac{N}{h}k_{\rm B}^2T_R^2\,{\rm Li}_2(-1) + \ldots \quad \text{for} \quad \mu_R-\mu_L \to +\infty\ . \tag{25}$$

For arbitrary large difference of the chemical potentials, it is evident that no bound occurs for the intensity of the left thermal current. This is different from the situation of thermal machine, where an upper bound occurs for the left thermal current.

C. Quantum bound for the right thermal current

By proceeding as above, the right thermal current is

$$I_Q^{(R)} = \frac{N}{h}\int_{\mu_R}^{\varepsilon_0} dE\,(E-\mu_R) f_{LR}(E)\ . \tag{26}$$

After some algebra, we obtain the expression

$$\begin{aligned} I_Q^{(R)} = \frac{N}{h}\Big[&k_{\rm B}^2(T_L^2-T_R^2)\,{\rm Li}_2(-{\rm e}^{-x_0}) - k_{\rm B}^2 T_R(T_L-T_R)x_0\ln(1+{\rm e}^{-x_0}) \\ &- k_{\rm B}^2 T_L^2\,{\rm Li}_2(-{\rm e}^{-x_1}) + k_{\rm B}^2 T_R^2\,{\rm Li}_2(-1)\Big]\ . \end{aligned} \tag{27}$$

We have that

$$I_Q^{(R)} = \frac{N}{h}\,k_{\rm B}^2T_R^2\,{\rm Li}_2(-1) + \ldots \quad \text{for} \quad \mu_R-\mu_L \to +\infty\ . \tag{28}$$

In conclusion, a quantum bound exists for the negative right thermal current

$$\left|I_Q^{(R)}\right| < \frac{N\pi^2}{12}\,\frac{k_{\rm B}^2}{h}\,T_R^2 \equiv I_Q^{R(QB)}\ . \tag{29}$$

The above result is in agreement with that reported in Eq.(58) of ref.[42], considering that we define

$$I_Q^{R(QB)} = \frac{1}{2}\,I_Q^{(\rm Pendry)}\ . \tag{30}$$

V. QUANTUM TRANSPORT IN A THERMAL MACHINE AT LOW-POWER OUTPUT.

We consider quantum transport through a device in the low-power generation regime, i.e., in the case $\mathcal{P} \approx 0^+$. The ideal low-power generation regime is obtained restricting the integral in Eq. (1b) to the positive region of $f_{LR}(E)$, and assuming the value of N for the transmission function in the small domain $[\varepsilon_0, \varepsilon_0 + \Delta]$ (i.e., a *box-car shape* of width Δ, where we expect maximum efficiency, see Fig. 1). Namely, we assume $\mathcal{T}(E) = N$ for $\varepsilon_0 < E < \varepsilon_0 + \Delta$, with $\Delta \to 0^+$, and $\mathcal{T}(E) = 0$ otherwise. The low-power output becomes

$$\mathcal{P}_{out} = \frac{N}{h}\,(\mu_R - \mu_L) \int_{\varepsilon_0}^{\varepsilon_0+\Delta} dE\, f_{LR}(E)\ . \tag{31}$$

Proceeding as in App. C, one can show that the final result is

$$\mathcal{P}_{out} = \frac{N}{h}(\mu_R - \mu_L)\left[\frac{\Delta^2(T_L - T_R)}{2k_{\rm B}T_LT_R}\psi'(x_0) + \frac{\Delta^3(T_L^2 - T_R^2)}{6k_{\rm B}^2T_L^2T_R^2}\psi''(x_0) + O(\Delta^4)\right]\ , \tag{32}$$

where $\psi(x) = -1/(e^x + 1)$.

A. Left thermal current in low-power ideal generators

Following App. C, the left thermal current is

$$\begin{aligned} I_Q^{(L)} &= \frac{N}{h}\int_{\varepsilon_0}^{\varepsilon_0+\Delta} dE\,(E - \mu_L) f_{LR}(E) \\ &= \frac{N}{h}(\mu_R - \mu_L)\frac{T_L}{T_L - T_R}\left[\frac{\Delta^2(T_L - T_R)}{2k_{\rm B}T_LT_R} + \psi'(x_0) + \frac{\Delta^3(T_L^2 - T_R^2)}{6k_{\rm B}^2T_L^2T_R^2}\,\psi''(x_0)\right] \\ &\quad + \frac{N}{h}\frac{\Delta^3(T_L - T_R)}{3k_{\rm B}T_LT_R}\,\psi'(x_0) + O(\Delta^4)\ . \end{aligned} \tag{33}$$

By using Eq. (32), we obtain the more effective form

$$I_Q^{(L)} = \frac{T_L}{T_L - T_R}\,\mathcal{P}_{out} + \frac{N}{h}\frac{\Delta^3(T_L - T_R)}{3k_{\rm B}T_LT_R}\ \psi'(x_0) + O(\Delta^4)\ , \tag{34}$$

which exactly coincides with Eq.(47) of ref.[42].

B. Efficiency of low-power thermal machines

We can divide both members of Eq. (34) by $I_Q^{(L)}$ and obtain

$$\eta^{(tm)} = \frac{\mathcal{P}_{out}}{I_Q^{(L)}} = \frac{T_L - T_R}{T_L}\left[1 - \frac{N}{h}\frac{\Delta^3(T_L - T_R)}{3k_{\rm B}T_LT_R}\,\psi'(x_0)\frac{1}{I_Q^{(L)}}\right]. \tag{35}$$

Linear corrections in the Δ parameter can be obtained expressing $I_Q^{(L)}$ to quadratic terms in Δ from Eq. (33). Eventually, we find

$$\eta^{(tm)} = \eta_c^{(tm)}\left[1 - \frac{2}{3}\,\frac{\Delta}{k_{\rm B}T_Lx_0} + O(\Delta^2)\right] \tag{36}$$

thus recovering Eq.(49) of ref.[42].

C. Efficiency of low-power thermal machines at fixed power output

The expression for the power production of the low-power thermal machine is given by Eq. (32). At the lowest (quadratic) order in Δ, the usable power reads

$$\mathcal{P}_{out} = \frac{N}{h}\, x_0\, \frac{\Delta^2 (T_L - T_R)^2}{2T_L T_R}\, \psi'(x_0)\ . \tag{37}$$

It is convenient to normalize the output power with the quantum bound obtained in Eq. (11), i.e.,

$$\frac{\mathcal{P}_{out}}{\mathcal{P}_{out}^{(QB)}} = \frac{1}{C_0}\, \frac{\Delta^2}{2k_{\rm B}^2 T_L T_R}\, x_0 \psi'(x_0)\ . \tag{38}$$

By combining Eq. (36) with the above equation, we obtain

$$\eta^{(tm)} = \eta_c^{(tm)} \left[1 - \frac{2}{3}\sqrt{2C_0}\, \sqrt{\frac{T_R}{T_L}\, \frac{\mathcal{P}_{out}}{\mathcal{P}_{out}^{(QB)}}}\, \frac{1}{\sqrt{x_0^3 \psi'(x_0)}} \right]. \tag{39}$$

The last step to be performed is the maximization of the above expression.

D. Optimization of the efficiency of low-power thermal machine at fixed power output

Optimization of the efficiency at given temperatures requires the maximization of the function $H(x_0) = x_0^3\, \psi'(x_0)$, which appears in the denominator of Eq. (39). With standard methods, we find

$$\bar{x}_0 = 3.24 \quad \text{and} \quad H(\bar{x}_0) = 1.234\ . \tag{40}$$

Since, according to Eq. (11), $C_0 = 0.316$, we have $(2/3)\sqrt{2C_0/H(\bar{x}_0)} = 0.477$ and finally

$$\eta^{(tm)} = \eta_c^{(tm)} \left[1 - 0.477 \sqrt{\frac{T_R}{T_L}}\, \sqrt{\frac{\mathcal{P}_{out}}{\mathcal{P}_{out}^{(QB)}}} \right]\ . \tag{41}$$

This relation coincides with Eq.(51) of ref.[42].

VI. QUANTUM TRANSPORT IN A REFRIGERATOR AT LOW-COOLING REGIME

The ideal low-power refrigerator ($\mathcal{P} \approx 0^-$) is obtained restricting the integral to the negative region of $f_{LR}(E)$, and assuming the value of N for the transmission function in the small domain $[\varepsilon_0 - \Delta, \varepsilon_0]$, where we expect maximum efficiency, see Fig. 2, i.e., we assume $\mathcal{T}(E) = N$ for $\varepsilon_0 - \Delta < E < \varepsilon_0$ and $\mathcal{T}(E) = 0$ otherwise, with $\Delta \to 0^+$. For the low-cooling refrigerator, the absorbed power is then

$$\mathcal{P}_{in} = \frac{N}{h}\, (\mu_R - \mu_L) \int_{\varepsilon_0 - \Delta}^{\varepsilon_0} dE\, f_{LR}(E)\ . \tag{42}$$

With an eye to App. C, the power absorption becomes

$$\mathcal{P}_{in} = \frac{N}{h}(\mu_R - \mu_L) \left[-\frac{\Delta^2 (T_L - T_R)}{2k_{\rm B} T_L T_R} \psi'(x_0) + \frac{\Delta^3 (T_L^2 - T_R^2)}{6k_{\rm B}^2 T_L^2 T_R^2} \psi''(x_0) \right] + O(\Delta^4)\ . \tag{43}$$

A. Right thermal current for an ideal refrigerator in the low-cooling regime

In the present conditions, the right thermal current is

$$I_Q^{(R)} = \frac{N}{h}\int_{\varepsilon_0-\Delta}^{\varepsilon_0} dE\,(E-\mu_R) f_{LR}(E)$$

$$= \frac{N}{h}(\mu_R-\mu_L)\frac{T_R}{T_L-T_R}\left[-\frac{\Delta^2(T_L-T_R)}{2k_{\rm B}T_LT_R}\,\psi'(x_0)+\frac{\Delta^3(T_L^2-T_R^2)}{6k_{\rm B}^2T_L^2T_R^2}\,\psi''(x_0)\right]$$

$$+\frac{N}{h}\frac{\Delta^3(T_L-T_R)}{3k_{\rm B}T_LT_R}\,\psi'(x_0)+O(\Delta^4)\ . \tag{44}$$

By exploiting Eq. (43) for $\mathcal{P}_{in}$, Eq. (44) can be cast in the more effective form

$$I_Q^{(R)} = \frac{T_R}{T_L-T_R}\,\mathcal{P}_{in}+\frac{N}{h}\frac{\Delta^3(T_L-T_R)}{3k_{\rm B}T_LT_R}\,\psi'(x_0)\ . \tag{45}$$

This equation coincides with Eq.(59) of ref.[42], where T_R and T_L are exchanged.

B. Efficiency of an ideal refrigerator in the low-cooling regime

The general expression for the efficiency of the refrigerator machine reads

$$\eta^{(refr)} = \frac{I_Q^{(R)}}{\mathcal{P}_{in}} = \frac{T_R}{T_L-T_R}\left[1+\frac{N}{h}\frac{\Delta^3(T_L-T_R)^2}{3k_{\rm B}T_LT_R^2}\,\psi'(x_0)\frac{1}{\mathcal{P}_{in}}\right]. \tag{46}$$

Correction linear in the Δ parameter can be obtained expressing $\mathcal{P}_{in}$ to quadratic terms in Δ. From Eq. (43) it holds

$$\mathcal{P}_{in} = -\frac{N}{h}(\mu_R-\mu_L)\frac{\Delta^2(T_L-T_R)}{2k_{\rm B}T_LT_R}\,\psi'(x_0)+O(\Delta^3) \tag{47}$$

Inserting Eq. (47) into Eq. (46) gives

$$\eta^{(refr)} = \eta_c^{(refr)}\left[1-\frac{2}{3}\,\frac{\Delta}{k_{\rm B}T_Rx_0}+O(\Delta^2)\right], \tag{48}$$

which corresponds to Eq.(61) of ref.[42].

C. Efficiency of the low-cooling refrigerator at fixed power input

The expression for the right thermal current of the low-power refrigeration machine is given by Eq. (44). At the lowest (quadratic) order in Δ, the right thermal current reads

$$I_Q^{(R)} = -\frac{N}{h}\,x_0\,\frac{\Delta^2(T_L-T_R)}{2T_L}\,\psi'(x_0)\ . \tag{49}$$

As done in Eq.(20) of ref.[42], we normalize the right thermal current as

$$\frac{I_Q^{(R)}}{I_Q^{(\rm Pendry)}} = \frac{1}{2C_1}\,\frac{\Delta^2(T_L-T_R)}{k_{\rm B}^2T_L^2T_R^2}\,x_0\psi'(x_0) \qquad \text{with} \qquad C_1=\frac{\pi^2}{6}\ . \tag{50}$$

The expression of Δ from the above equation can be inserted in Eq. (46) and one obtains

$$\eta^{(refr)} = \eta_c^{(refr)}\left[1-\frac{2}{3}\,\sqrt{2C_1}\,\sqrt{\frac{T_L}{T_L-T_R}\,\frac{I_Q^{(R)}}{I_Q^{(\rm Pendry)}}}\,\frac{1}{\sqrt{x_0^3\psi'(x_0)}}\right]. \tag{51}$$

The last step to be performed is the maximization of the above expression.

	Ideal thermal machine	Ideal refrigerator
$\mathcal{T}(E)$	$\mathcal{T}(E) := \begin{cases} N, & E \geq \varepsilon_0 \\ 0, & E < \varepsilon_0 \end{cases}$	$\mathcal{T}(E) := \begin{cases} N, & \mu_R \leq E \leq \varepsilon_0 \\ 0, & \text{Otherwise} \end{cases}$
$\mathcal{P}^{(QB)}$	$\mathcal{P}^{(QB)}_{out} = C_0 \frac{N}{h} k_{\rm B}^2 (T_L - T_R)^2$	Absence of bound for $\mathcal{P}_{in}$
$I_Q^{(L)(QB)}$	$\frac{N\pi^2}{12} \frac{k_{\rm B}^2}{h} (T_L^2 - T_R^2)$	Absence of bound for $I_Q^{(L)}$
$I_Q^{(R)(QB)}$	$\frac{N\pi^2}{12} \frac{k_{\rm B}^2}{h} (T_L^2 - T_R^2)$	$\frac{N\pi^2}{12} \frac{k_{\rm B}^2}{h} T_R^2$
η	$\eta^{(tm)} \rightarrow \quad \eta_{\rm C}^{(tm)}$	Absence of bound for $\eta^{(refr)}$

TABLE I. Transmission functions, quantum bounds and efficiency for the ideal thermal machine and for the ideal refrigerator.

D. Optimization of the efficiency of the low-power refrigerator at fixed power absorption

Optimization of the efficiency at fixed temperatures requires in essence the maximization of the function $H(x_0) = x_0^3 \psi'(x_0)$, with $H(x_0) > 0$. This function appears in the denominator of Eq. (51). This can be done repeating step by step the same process used for the case of the low-power thermal machine at fixed power output in Section V. In particular, by exploiting the value of the coefficient $C_1 = 1.645$ we obtain $(2/3)\sqrt{2C_1/H(x_0)} = 1.088$. Finally, the maximal value of Eq. (46) is

$$\eta^{(refr)} = \eta_c^{(refr)} \left[1 - 1.088 \sqrt{\frac{T_L}{T_L - T_R} \frac{I_Q^{(R)}}{I_Q^{(\rm Pendry)}}} \right] , \tag{52}$$

which recovers exactly Eq.(63) of ref.[42].

VII. CONCLUSIONS

We have presented the analytic details for the evaluation of quantum bounds in the response functions of thermoelectric machines.

We have considered a two-terminal macroscopic device operating between two reservoirs at different temperatures and chemical potentials. The electronic transport in the device is modelled by the Landauer scattering theory and the electronic transmission function $\mathcal{T}(E)$ is assumed to be of step-like shape or box-like shape, in the case of power generation machine or refrigerator machine, respectively, so to guarantee the condition of upper bound value of the thermoelectric parameters. The expressions obtained are summarized in tables I and II.

We hope that the present analysis of currents and quantum bounds can be useful for highlighting the formal aspects of the results obtained in the literature.

Low-power output ideal thermal machine	Refrigerator in the low-cooling regime
$\mathcal{T}(E) := \begin{cases} N, & \varepsilon_0 \le E \le \varepsilon_0 + \Delta, \quad \Delta \to 0^+ \\ 0, & \text{Otherwise} \end{cases}$	$\mathcal{T}(E) := \begin{cases} N, & \varepsilon_0 - \Delta \le E \le \varepsilon_0, \quad \Delta \to 0^+ \\ 0, & \text{Otherwise} \end{cases}$
$\eta^{(tm)} \sim \eta_{\mathrm{C}}^{(tm)} \left[0.477 \sqrt{\frac{T_R}{T_L}} \sqrt{\frac{\mathcal{P}_{out}}{\mathcal{P}_{out}^{(QB)}}} \right]$	$\eta^{(refr)} \sim \eta_{\mathrm{C}}^{(refr)} \left[1 - 1.088 \sqrt{\frac{T_L}{T_L - T_R} \frac{I_Q^{(R)}}{I_Q^{(R)(QB)}}} \right]$

TABLE II. Transmission functions and maximum efficiencies for the ideal thermal machine and the refrigerator in the low-power and low-cooling regimes, respectively.

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Appendix A: Polylogarithms basic properties

The poly-logarithm function of order unit is defined in terms of the standard logarithm as[53]

$$\mathrm{Li}_1(z) \equiv -\ln(1-z) = \sum_1^\infty \frac{z^n}{n} \ , \tag{A1}$$

$|z| < 1$. In general, one defines the polylog of order k as

$$\mathrm{Li}_k(z) \equiv \int_0^z \frac{\mathrm{Li}_{k-1}(t)}{t} \, \mathrm{d}\, t = \sum_1^\infty \frac{z^n}{n^k} \qquad k = 2, 3, \dots \tag{A2}$$

where again the series expansion is valid in the $|z| < 1$ region. These functions inherit from the logarithm the branch point at $z = 1$ and the cut along the positive real axis $[1, +\infty)$. Considering $z = -\,\mathrm{e}^{-x}$ one obtains

$$\frac{d}{dx} \mathrm{Li}_m(-\,\mathrm{e}^{-x}) = -\,\mathrm{Li}_{m-1}(-\,\mathrm{e}^{-x}) \qquad m = 1, 2, \dots \tag{A3}$$

Notice in particular that

$$\mathrm{Li}_0(-\,\mathrm{e}^{-x}) = -\frac{d}{dx} \mathrm{Li}_1(-\,\mathrm{e}^{-x}) = -\frac{1}{\mathrm{e}^x + 1} \ . \tag{A4}$$

The above functions are useful for calculating integrals related to the Fermi functions. In fact

$$\int \frac{1}{\mathrm{e}^x + 1} \, \mathrm{d}\, x = -\int \mathrm{Li}_0(-\,\mathrm{e}^{-x}) \, \mathrm{d}\, x = \mathrm{Li}_1(-\,\mathrm{e}^{-x}) = -\ln(1 + \mathrm{e}^{-x}) \tag{A5}$$

and integrating by parts

$$\begin{aligned} \int \frac{x}{\mathrm{e}^x + 1} \, \mathrm{d}\, x &= \int x \frac{d}{dx} \mathrm{Li}_1(-\,\mathrm{e}^{-x}) \, \mathrm{d}\, x = x \, \mathrm{Li}_1(-\,\mathrm{e}^{-x}) - \int \mathrm{Li}_1(-\,\mathrm{e}^{-x}) \, \mathrm{d}\, x \\ &= -x \ln(1 + \mathrm{e}^{-x}) + \mathrm{Li}_2(-\,\mathrm{e}^{-x}) \ . \end{aligned} \tag{A6}$$

Asymptotic behaviors[53] for $x \to +\infty$ can be obtained easily as

$$\mathrm{Li}_1(-\mathrm{e}^{-x}) = -\mathrm{e}^{-x} + O(\mathrm{e}^{-2x}) \qquad \text{and} \qquad \mathrm{Li}_2(-\mathrm{e}^{-x}) = -\mathrm{e}^{-x} + O(\mathrm{e}^{-2x}) \,, \tag{A7}$$

moreover, for $x \to -\infty$

$$\mathrm{Li}_1(-\mathrm{e}^{-x}) = x - \mathrm{e}^{x} + O(\mathrm{e}^{2x}) \qquad \text{and} \qquad \mathrm{Li}_2(-\mathrm{e}^{-x}) = -\frac{\pi^2}{6} - \frac{x^2}{2} + \mathrm{e}^{x} + O(\mathrm{e}^{2x}) \,. \tag{A8}$$

Appendix B: Currents and power related integrals

Let us introduce two primitive functions involving the Fermi function

$$g(E) \equiv \int \frac{1}{\mathrm{e}^{\beta(E-\mu)}+1}\,\mathrm{d}\,E = \frac{1}{\beta}\,\mathrm{Li}_1(-\mathrm{e}^{-\beta(E-\mu)}) \tag{B1}$$

and

$$h(E) \equiv \int \frac{E}{\mathrm{e}^{\beta(E-\mu)}+1}\,\mathrm{d}\,E = Eg(E) + \frac{1}{\beta^2}\,\mathrm{Li}_2(-\mathrm{e}^{-\beta(E-\mu)}) \,, \tag{B2}$$

which follow from (A5) and (A6), respectively, and $\beta = 1/k_\mathrm{B}T$. Notice that both $g(E)$ and $h(E)$ are exponentially small when $E \to +\infty$.

With the help of (B1) and (B2) we can quickly express the integrals reported in the main text. In fact

$$\int f_{LR}(E)\,\mathrm{d}\,E = g_L(E) - g_R(E) \tag{B3a}$$

$$\begin{aligned}\int (E-\mu) f_{LR}(E)\,\mathrm{d}\,E &= h_L - h_R - \mu(g_L - g_R) \\ &= (E-\mu)(g_L(E) - g_R(E)) \\ &\quad + \beta_L^{-2}\,\mathrm{Li}_2(-\mathrm{e}^{-\beta_L(E-\mu_L)}) - \beta_R^{-2}\,\mathrm{Li}_2(-\mathrm{e}^{-\beta_R(E-\mu_R)}) \,,\end{aligned} \tag{B3b}$$

where $g_{L,R}(E)$ mean that $g(E)$ is calculated in correspondence of $T_{L,R}$ and $\mu_{L,R}$. From application of expressions (B3) we recover the results reported in the main text. For example, for the left current in the thermal machine mode we need to evaluate

$$\begin{aligned}\int_{\epsilon_0}^{+\infty} (E-\mu_L) f_{LR}(E)\,\mathrm{d}\,E &= -(\epsilon_0 - \mu_L)(g_L(\epsilon_0) - g_R(\epsilon_0)) + \\ &\quad - \beta_L^{-2}\,\mathrm{Li}_2(-\mathrm{e}^{-\beta_L(\epsilon_0-\mu_L)}) + \beta_R^{-2}\,\mathrm{Li}_2(-\mathrm{e}^{-\beta_R(\epsilon_0-\mu_R)}) \\ &= k_\mathrm{B}^2 T_L(T_L - T_R)\,x_0\,\ln(1+\mathrm{e}^{-x_0}) - k_\mathrm{B}^2(T_L^2 - T_R^2)\,\mathrm{Li}_2(-\mathrm{e}^{-x_0}) \,,\end{aligned} \tag{B4}$$

where we exploited the asymptotic expressions (A7) and the definition of ϵ_0 and x_0 given in the main text.

In the refrigerator mode the expressions are more involved, because both integration limits are finite. For the left current we need

$$\begin{aligned}\int_{\mu_r}^{\epsilon_0} (E-\mu_L) f_{LR}(E)\,\mathrm{d}\,E &= (\epsilon_0 - \mu_L)(g_L(\epsilon_0) - g_R(\epsilon_0)) - (\mu_R - \mu_L)(g_L(\mu_R) - g_R(\mu_R)) \\ &\quad + \beta_L^{-2}[\mathrm{Li}_2(-\mathrm{e}^{-x_0}) - \mathrm{Li}_2(-\mathrm{e}^{-x_1})] - \beta_R^{-2}[\mathrm{Li}_2(-\mathrm{e}^{-x_0}) - \mathrm{Li}_2(-1)] \,.\end{aligned} \tag{B5}$$

After some algebra, one obtains

$$\begin{aligned}\int_{\mu_r}^{\epsilon_0} (E-\mu_L) f_{LR}(E)\,\mathrm{d}\,E &= k_\mathrm{B}^2(T_L - T_R)\,x_0\left[-\ln(2)\,T_R + T_L(\ln(1+\mathrm{e}^{-x_1}) - \ln(1+\mathrm{e}^{-x_0}))\right] \\ &\quad + k_\mathrm{B}^2(T_L^2 - T_R^2)\,\mathrm{Li}_2(-\mathrm{e}^{-x_0}) - k_\mathrm{B}^2 T_L^2\,\mathrm{Li}_2(-\mathrm{e}^{-x_1}) - \frac{\pi^2}{12}k_\mathrm{B}^2 T_R^2 \,,\end{aligned} \tag{B6}$$

as reported in the main text. The same procedure gives for the right current

$$\begin{aligned}\int_{\mu_r}^{\epsilon_0}(E-\mu_R)f_{LR}(E)\,\mathrm{d}\,E &= (\epsilon_0-\mu_R)(g_L(\epsilon_0)-g_R(\epsilon_0))\\ &\quad+\beta_L^{-2}[\mathrm{Li}_2(-\mathrm{e}^{-x_0})-\mathrm{Li}_2(-\mathrm{e}^{-x_1})]-\beta_R^{-2}[\mathrm{Li}_2(-\mathrm{e}^{-x_0})-\mathrm{Li}_2(-1)]\\ &= -k_\mathrm{B}^2T_R(T_L-T_R)\,x_0\ln(1+\mathrm{e}^{-x_0})\\ &\quad+k_\mathrm{B}^2(T_L^2-T_R^2)\,\mathrm{Li}_2(-\mathrm{e}^{-x_0})-k_\mathrm{B}^2T_L^2\,\mathrm{Li}_2(-\mathrm{e}^{-x_1})-\frac{\pi^2}{12}k_\mathrm{B}^2T_R^2\ .\end{aligned} \tag{B7}$$

For the input power, the integral is

$$\begin{aligned}(\mu_R-\mu_L)\int_{\mu_r}^{\epsilon_0}f_{LR}(E)\,\mathrm{d}\,E &= (\mu_R-\mu_L)(g_{LR}(\epsilon_0)-g_{LR}(\mu_R))\\ &= k_\mathrm{B}^2(T_L-T_R)x_0\left[-\ln(2)\,T_R+(T_L-T_R)\ln(1+\mathrm{e}^{-x_0})+T_L\ln(1+\mathrm{e}^{-x_1})\right]\ .\end{aligned} \tag{B8}$$

Appendix C: The low power regime

In this regime the integration limits are very close. This means that we can use the Taylor expansion of the g and h functions introduced in (B1) and (B2). The procedure is quite similar for all the needed integrals, so we present some details only for one case. For instance, for the power in the thermal machine mode we need

$$\begin{aligned}\int_{\epsilon_0}^{\epsilon_0+\Delta}f_{LR}(E)\,\mathrm{d}\,E &= g_{LR}(\epsilon_0+\Delta)-g_{LR}(\Delta)\\ &= g'_{LR}(\epsilon_0)\Delta+g''_{LR}(\epsilon_0)\frac{\Delta^2}{2}+g'''_{LR}(\epsilon_0)\frac{\Delta^3}{6}+O(\Delta^4)\\ &= f_{LR}(\epsilon_0)\Delta+f'_{LR}(\epsilon_0)\frac{\Delta^2}{2}+f''_{LR}(\epsilon_0)\frac{\Delta^3}{6}+O(\Delta^4)\ .\end{aligned} \tag{C1}$$

Now using the fact that $f_{LR}(\epsilon_0)=0$ and the function $\psi(x)=-1/(\mathrm{e}^x+1)$ as defined in the main text, we find

$$f'_{LR}(\epsilon_0)=(\beta_L-\beta_R)\frac{-\mathrm{e}^{x_0}}{(\mathrm{e}^{x_0}+1)^2}=\frac{T_L-T_R}{k_\mathrm{B}T_LT_R}\,\psi'(x_0) \tag{C2}$$

$$f''_{LR}(\epsilon_0)=(\beta_L^2-\beta_R^2)\frac{\mathrm{e}^{x_0}(\mathrm{e}^{x_0}-1)}{(\mathrm{e}^{x_0}+1)^3}=\frac{T_L^2-T_R^2}{k_\mathrm{B}^2T_L^2T_R^2}\,\psi''(x_0) \tag{C3}$$

and finally

$$\int_{\epsilon_0}^{\epsilon_0+\Delta}f_{LR}(E)\,\mathrm{d}\,E=\frac{T_L-T_R}{2k_\mathrm{B}T_LT_R}\,\psi'(x_0)\Delta^2+\frac{T_L^2-T_R^2}{6k_\mathrm{B}^2T_L^2T_R^2}\,\psi''(x_0)\Delta^3+O(\Delta^4) \tag{C4}$$

as used in (32).

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